

Non-linear model of impurity diffusion in nanoporous materials upon ultrasonic treatment

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Non-linear theory of diffusion of impurities in porous materials upon ultrasonic treatment is described. It is shown that at a defined value of deformation amplitude, an average concentration of vacancies and temperature as a result of the effect of ultrasound possibly leads to the formation of nanoclusters of vacancies and to their periodic educations in porous materials. It is shown that at a temperature smaller than some critical value, a significant growth of a diffusion coefficient is observed in porous materials.

Key words: *diffusion coefficient, ultrasound, vacancy, pore*

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1. Introduction

It is known that in an ultrasonically treated solid, the concentration of defects, in particular the concentration of vacancies nonlinearly depends on both temperature and acoustic vibration intensity [1, 2]. Moreover, in a certain ultrasonic and temperature range, one can observe a significant increase (more than by one order) of the defect structure of a sample, i.e., the acoustic effect is clearly synergetic in this case. In work [1] it has been demonstrated that the equilibrium vacancy concentration can be high even at low temperatures, if the bulk deformation exceeds some critical value. The processes of self-organization of vacancies (that interact with one another and with the crystalline matrix through the deformation field) into separate clusters and periodic structures is possible if their concentration is high enough [3]. The formation of a periodic pore lattice in metal and in dielectric materials irradiated with high-energy neutron and electron beams has been observed in works [4, 5].

In works [6–8] it has been demonstrated that by means of a supersonic wave one can control the transport properties of semiconductors and change their structure due to the processes of impurity atom diffusion, dissolution and the formation of complexes, as well as the formation of impurity atom clusters and intrinsic defects in periodic deformation fields.

Extrinsic heterogeneous deformation causes the change of point defect chemical potential and leads to the directional diffusion flows. In work [9] it has been empirically determined that Si ultrasonic processing can stimulate a diffusion at room temperature. A significant increase (more than $2 \div 3$ times larger) of carbon diffusion coefficient in steel is observed at a fixed temperature in a certain range of acoustic vibration amplitude [10].

In this work, a nonlinear diffusion deformation theory of vacancy cluster formation in ultrasonically treated porous material is made, in order to specify the ultrasonic effect on the impurity diffusion coefficient.

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2. The model

We model a porous medium using a system of spherical particles (granules), the radius of which is $r_g = R_0 - r_0$, and the radius of impurities is r_d (figure 1 (a)), where $2r_0$ is the space between the granules, considered herein below as the pore diameter (figure 1 (b)). We select a cylindrical bulk element of a porous material (figure 1) with the radius R_0 and the cylindrical pore having the radius r_0 ($R_0 \gg r_0$). The average concentration of vacancies of this system is N_{d0} .

Considering the nonlocal Hooke's law [11], the energy of vacancy interaction with matrix atoms U_{da}^{int} through the elastic field can be determined as follows:

$$U_{da}^{int}(r) = - \int \lambda(|r' - r|) \varepsilon(r') \Delta \Omega_d dr', \quad (2.1)$$

where λ is the elastic moduli operator [3]. Introducing the variable $\tau = r' - r$ and expanding $\varepsilon(r + \tau)$ in a Taylor series by τ , we obtain:

$$\begin{aligned} U_{da}^{int}(r) &= - \int \lambda(|\tau|) \varepsilon(r + \tau) \Delta \Omega_d d\tau \\ &= - \int \lambda(|\tau|) \left[\varepsilon(r) + \frac{\partial^2 \varepsilon(r)}{\partial r^2} \frac{\tau^2}{2} \right] \Delta \Omega_d d\tau \\ &= -K \varepsilon(r) \Delta \Omega_d - K \frac{\partial^2 \varepsilon(r)}{\partial r^2} r_{da}^2 \Delta \Omega_d, \end{aligned} \quad (2.2)$$

where $K = \int \lambda(|\tau|) d\tau$ is an elasticity coefficient [3]; $r_{da} = \left[\frac{1}{2} \int \lambda(|\tau|) \tau^2 d\tau / \int \lambda(|\tau|) d\tau \right]^{1/2}$ is the characteristic length of interaction between the vacancy and matrix atoms; $\Delta \Omega_d$ is the crystalline volume change caused by one defect; $\varepsilon(r)$ is a strain tensor radial component. The elastic field of a solid acts on the vacancy with the force:

$$\begin{aligned} \vec{F} &= -\text{grad} U_{da}^{int} \\ &= K \text{grad} \left[\varepsilon(r) \Delta \Omega_d + \frac{\partial^2 \varepsilon(r)}{\partial r^2} r_{da}^2 \Delta \Omega_d \right]. \end{aligned} \quad (2.3)$$

Under this force, the defects in the elastic field get the velocity

$$\vec{v} = \mu \vec{F} = \frac{D_v K}{k_B T} \text{grad} \left[\varepsilon(r) \Delta \Omega_d + \frac{\partial^2 \varepsilon(r)}{\partial r^2} r_{da}^2 \Delta \Omega_d \right], \quad (2.4)$$

where μ , D_v are, respectively, the mobility and vacancy diffusion coefficient; T is the temperature; k_B is the Boltzmann constant. Here, we use the Einstein relation to determine the impurity mobility.

As we can see from (2.4), the vacancy velocity in the elastic field is determined by the deformation gradients and crystal volume gain due to these defects. Thus, the defects that are the compression centers ($\Delta \Omega_d < 0$), in particular the vacancies, will move to the area of the relative compression [the direction of the velocity vector of vacancy coincides with the direction of the vector $-\text{grad} \varepsilon(r)$].

Taking (2.4) into account, the stationary flow of vacancies can be presented as follows:

$$j = -D_v \frac{\partial N_d}{\partial r} + N_d \frac{D_v K}{k_B T} \left(\frac{\partial \varepsilon}{\partial r} \Delta \Omega_d + \frac{\partial^3 \varepsilon}{\partial r^3} r_{da}^2 \Delta \Omega_d \right). \quad (2.5)$$

The potential energy density of the elastic defect-free continuum that takes into account the anharmonic components can be presented as follows:

$$U_a = \frac{1}{2} E \varepsilon^2(r) + \frac{1}{3} E \alpha \varepsilon^3(r) + \frac{1}{4} E \beta \varepsilon^4(r) + E a_0^2 \frac{\partial^2 \varepsilon(r)}{\partial r^2} \varepsilon(r), \quad (2.6)$$

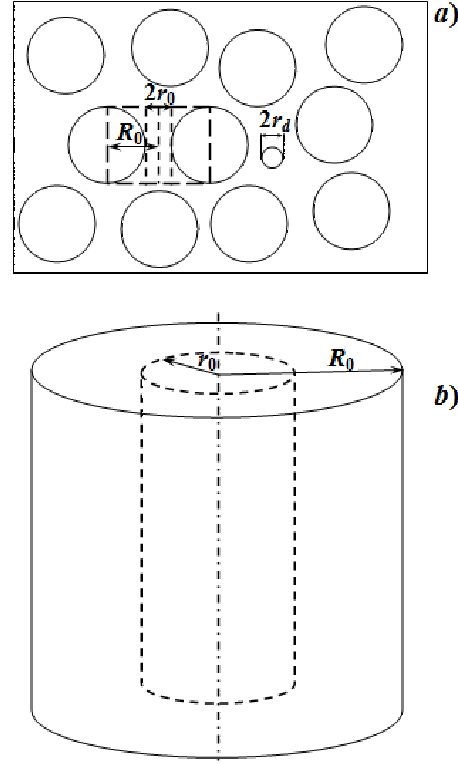


Figure 1. Geometrical model of a porous medium with impurity.

where E is the modulus of elasticity; α, β are the elastic anharmonicity constants; a_0 is the characteristic distance of the crystalline matrix atom interaction that is roughly equal to the matrix lattice parameter.

Then, taking into account (2.2) and (2.6), the free energy density of a crystal with vacancies can be presented as follows:

$$\begin{aligned} \Phi = U_a + N_d U_d^{\text{int}} - TS = & \frac{1}{2} E \varepsilon^2(r) + \frac{1}{3} E \alpha \varepsilon^3(r) + \frac{1}{4} E \beta \varepsilon^4(r) + E a_0^2 \frac{\partial^2 \varepsilon(r)}{\partial r^2} \varepsilon(r) \\ & - K N_d(r) \varepsilon(r) \Delta \Omega_d - K N_d(r) \frac{\partial^2 \varepsilon(r)}{\partial r^2} r_{\text{da}}^2 \Delta \Omega_d - TS, \end{aligned} \quad (2.7)$$

where S is the entropy density.

Applying the relation $\sigma = \partial \Phi / \partial \varepsilon$, we obtain the mechanical stress expression:

$$\sigma = E \varepsilon + E \alpha \varepsilon^2 + E \beta \varepsilon^3 + E a_0^2 \frac{\partial^2 \varepsilon}{\partial r^2} - K N_d \Delta \Omega_d. \quad (2.8)$$

The mechanical stress in an ultrasonically treated solid, subjected to the anharmonic components, is as follows:

$$\tilde{\sigma} = \sigma + E \varepsilon_0 \cos \omega t + E \alpha (\varepsilon_0 \cos \omega t)^2 + E \beta (\varepsilon_0 \cos \omega t)^3, \quad (2.9)$$

where ε_0 is an ultrasonically induced deformation amplitude. Here, the wavelength $\lambda \gg R_0$. Having averaged by the time, we obtain:

$$\begin{aligned} \tilde{\sigma} = E \varepsilon + E \alpha \varepsilon^2 \left(1 + \frac{\varepsilon_0^2}{2 \varepsilon^2} \right) + E \beta \varepsilon^3 + E a_0^2 \frac{\partial^2 \varepsilon}{\partial r^2} - K N_d \Delta \Omega_d \\ = E \varepsilon + E \tilde{\alpha} \varepsilon^2 + E \beta \varepsilon^3 + E a_0^2 \frac{\partial^2 \varepsilon}{\partial r^2} - K N_d \Delta \Omega_d, \end{aligned} \quad (2.10)$$

where $\tilde{\alpha} = \alpha (1 + \varepsilon_0^2 / 2 \varepsilon^2)$.

Let us present the vacancy concentration and deformation as follows:

$$N_d(r) = N_1(r) + N_0, \quad (2.11)$$

$$\varepsilon(r) = \varepsilon_1(r) + N_0 \Delta \Omega_d + \varepsilon_0 \cos \omega t, \quad (2.12)$$

where $N_1(r), \varepsilon_1(r)$ are the space inhomogeneous components of vacancy concentration and deformation, respectively; $N_1(r) \ll N_0$. Thus,

$$\tilde{\alpha} = \alpha \left[1 + \frac{\varepsilon_0^2}{2 (N_0 \Delta \Omega_d)^2 + \varepsilon_0^2} \right].$$

From the strained solid equilibrium condition $\partial \tilde{\sigma} / \partial r = 0$, we obtain the following deformation equation:

$$E \frac{\partial \varepsilon}{\partial r} + E \tilde{\alpha} \frac{\partial (\varepsilon^2)}{\partial r} + E \beta \frac{\partial (\varepsilon^3)}{\partial r} + E a_0^2 \frac{\partial^3 \varepsilon}{\partial r^3} - K \frac{\partial N_d}{\partial r} \Delta \Omega_d = 0. \quad (2.13)$$

Taking into account (2.5), the diffusion steady-state equation for vacancies can be written as follows:

$$\text{div} \left[D_v \frac{\partial N_d}{\partial r} - N_d \frac{D_v K}{k_B T} \left(\frac{\partial \varepsilon}{\partial r} \Delta \Omega_d + \frac{\partial^3 \varepsilon}{\partial r^3} r_{\text{da}}^2 \Delta \Omega_d \right) \right] + G_d - \frac{N_d}{\tau_d} = 0, \quad (2.14)$$

where G_d, τ_d are the generation rate and vacancy lifetime, respectively.

To find the vacancy concentration distribution and deformation in the investigated structure, one needs to solve the system of nonlinear differential equations (2.13) and (2.14). Substituting (2.11), (2.12) into (2.13), (2.14), and taking into account that $N_1(r) \ll N_0$ and at $r \rightarrow R_0$, the conditions $\partial N_1 / \partial r = 0$ and $\partial \varepsilon_1 / \partial r = 0$ must be kept, we obtain that $N_0 = G_d \tau_d$, and the equation for $N_1(r)$ and $\varepsilon_1(r)$ reads as follows:

$$D_v \frac{\partial N_1}{\partial r} - N_0 \frac{D_v \theta_v}{k_B T} \left(\frac{\partial \varepsilon_1}{\partial r} + \frac{\partial^3 \varepsilon_1}{\partial r^3} r_{\text{da}}^2 \right) = 0, \quad (2.15)$$

$$\frac{\partial \varepsilon_1}{\partial r} + \tilde{\alpha} \frac{\partial (\varepsilon_1^2)}{\partial r} + \beta \frac{\partial (\varepsilon_1^3)}{\partial r} + a_0^2 \frac{\partial^3 \varepsilon_1}{\partial r^3} - \frac{\theta_v}{E} \frac{\partial N_1}{\partial r} = 0, \quad (2.16)$$

where $\theta_v = K \Delta \Omega_d$ is the vacancy deformation potential.

Integrating the equation (2.15), we obtain:

$$N_1 = \frac{N_0 \theta_v}{k_B T} \left(\varepsilon_1 + \frac{\partial^2 \varepsilon_1}{\partial r^2} r_{da}^2 \right). \quad (2.17)$$

Substituting (2.17) into (2.16), we obtain the deformation equation that, after integration, can be written as follows:

$$\frac{\partial^2 \varepsilon_1}{\partial r^2} - a \varepsilon_1 + f \varepsilon_1^2 - c \varepsilon_1^3 = 0, \quad (2.18)$$

where

$$a = \frac{1 - \frac{N_0}{N_c}}{r_{da}^2 \left(\frac{N_0}{N_c} - \frac{a_0^2}{r_{da}^2} \right)}, \quad f = \frac{|\tilde{\alpha}|}{r_{da}^2 \left(\frac{N_0}{N_c} - \frac{a_0^2}{r_{da}^2} \right)}, \quad c = \frac{\beta}{r_{da}^2 \left(\frac{N_0}{N_c} - \frac{a_0^2}{r_{da}^2} \right)}, \quad N_c = \frac{E k_B T}{\theta_v^2}.$$

Here, we have taken into account that $\alpha < 0$, $\beta > 0$ [3].

3. Formation of vacancy nanoclusters and their periodic structures

The solution of the equation (2.18) is as follows:

$$r = \int \frac{d\varepsilon_1}{\sqrt{a\varepsilon_1^2 - \frac{2f\varepsilon_1^3}{3} + \frac{c\varepsilon_1^4}{2}}} + r_c,$$

where r_c is the constant of integration.

Making a substitution $\varepsilon_1 = \frac{1}{z}$, one can present this integral as follows:

$$r - r_c = - \int \frac{dz}{\sqrt{a \left(z - \frac{f}{3a} \right)^2 + \Delta}}, \quad (3.1)$$

where $\Delta = -f^2/(9a) + c/2$.

The integral (3.1) is expressed by analytic functions whose type we determine by the sign of the coefficients a and Δ .

If the following conditions are fulfilled:

$$\frac{N_0}{N_c} < \frac{a_0^2}{r_{da}^2} \quad \text{and} \quad \frac{2\tilde{\alpha}^2}{9\beta} < 1 - \frac{N_0}{N_c} \quad (a < 0 \quad \text{and} \quad \Delta < 0), \quad (3.2)$$

then $\varepsilon_1 = 0$, and $N(r) = N_0$, the distribution of vacancies is spatially homogeneous. Taking into account that $2\alpha^2/(9\beta) = 4/9$ [3] and $\tilde{\alpha} = \alpha \{1 + \varepsilon_0^2/[2(N_0 \Delta \Omega_d)^2 + \varepsilon_0^2]\}$, the conditions (3.2) can be written as follows:

$$\frac{N_0}{N_c} < \frac{a_0^2}{r_{da}^2} \quad \text{and} \quad \varepsilon_0^2 < \left(\frac{\sqrt{2} k_B T}{\theta_v} \right)^2 \left(\frac{N_0}{N_c} \right)^2 \left(\frac{1}{\frac{3}{2} \sqrt{1 - \frac{N_0}{N_c}} - 1} - 1 \right)^{-1}. \quad (3.3)$$

If the average defect concentration exceeds the value $N_0 = N_c a_0^2 / r_{da}^2$, whatever is the supersonic wave deformation amplitude, the spatially nonuniform solution becomes unstable, and there appears a new spatially nonuniform stationary state (i.e., the formation of clusters or periodic vacancy structures).

Moreover, if the second condition in (3.3) is not fulfilled, vacancy clusters will always appear. If the concentration of clusters or periodic vacancy structures is constant, then their formation conditions depend on the temperature. In particular, the conditions (3.3) can be written as follows:

$$\frac{T_c}{T} < \frac{a_0^2}{r_{da}^2}, \quad \varepsilon_0^2 < \left(\frac{\sqrt{2}k_B T_c}{\theta_v} \right)^2 \left(\frac{1}{\frac{3}{2}\sqrt{1-\frac{T_c}{T}}-1} - 1 \right)^{-1}, \quad (3.4)$$

where $T_c = \theta_v^2 N_0 / (Ek_B)$.

In other cases, depending on the values $N_0(T)$ and ε_0 , the solution of the equation (2.18) will be as follows:

- $a > 0$ and $\Delta > 0$:

$$\varepsilon_1(r) = -\frac{A}{B + \text{sh}[\sqrt{a}(r-r_0)]} \quad \text{at} \quad \frac{a_0^2}{r_{da}^2} < \frac{N_0}{N_c} < 1 - \frac{2\tilde{a}^2}{9\beta} \quad \text{and}$$

$$\varepsilon_0^2 < \left(\frac{\sqrt{2}k_B T}{\theta_v} \right)^2 \left(\frac{N_0}{N_c} \right)^2 \left(\frac{1}{\frac{3}{2}\sqrt{1-\frac{N_0}{N_c}}-1} - 1 \right)^{-1}; \quad (3.5)$$

- $a > 0$ and $\Delta < 0$:

$$\varepsilon_1(r) = -\frac{A}{B + \text{ch}[\sqrt{a}(r-r_0)]} \quad \text{at} \quad 1 - \frac{2\tilde{a}^2}{9\beta} < \frac{N_0}{N_c} < 1 \quad \text{and}$$

$$\varepsilon_0^2 < \left(\frac{\sqrt{2}k_B T}{\theta_v} \right)^2 \left(\frac{N_0}{N_c} \right)^2 \left(\frac{1}{\frac{3}{2}\sqrt{1-\frac{N_0}{N_c}}-1} - 1 \right)^{-1},$$

or at

$$\frac{a_0^2}{r_{da}^2} < \frac{N_0}{N_c} < 1 - \frac{2\tilde{a}^2}{9\beta}, \quad \varepsilon_0^2 > \left(\frac{\sqrt{2}k_B T}{\theta_v} \right)^2 \left(\frac{N_0}{N_c} \right)^2 \left(\frac{1}{\frac{3}{2}\sqrt{1-\frac{N_0}{N_c}}-1} - 1 \right)^{-1}; \quad (3.6)$$

- $a < 0$ and $\Delta > 0$:

$$\varepsilon_1(r) = -\frac{A}{B + \sin[\sqrt{|a|}(r-r_0)]} \quad \text{at} \quad \frac{N_0}{N_c} > 1,$$

or at

$$\varepsilon_0^2 > \left(\frac{\sqrt{2}k_B T}{\theta_v} \right)^2 \left(\frac{N_0}{N_c} \right)^2 \left(\frac{1}{\frac{3}{2}\sqrt{1-\frac{N_0}{N_c}}-1} - 1 \right)^{-1} \quad \text{and} \quad \frac{N_0}{N_c} < \frac{a_0^2}{r_{da}^2}, \quad (3.7)$$

where $A = 3\sqrt{2}|a|(|9ca - 2f^2|)^{-\frac{1}{2}}$, $B = \sqrt{2}f(|9ca - 2f^2|)^{-\frac{1}{2}}$.

The constant of integration r_c is chosen for the reason that the maximum vacancy clustering occurs at the pore surface, so that the condition $r_c = r_0$ is fulfilled.

Thus, vacancy clusters or their periodic structures are formed at certain values of the defect concentration N_0 (or the temperature T) and supersonic wave amplitude ε_0 . In figure 2, the areas of possible formation of vacancy clusters depending on the values ε_0^2 and $N_0/N_c (T_c/T)$ are plotted. The calculations are made for the following parameter values: $a_0^2/r_{da}^2 = 0.01$; $\sqrt{2}k_B T/\theta_v = 0.01$. At the average defect concentration $N_0 > N_c$ (or the temperature $T < T_c$) in porous material, periodic defect-deformation structures are formed (even at $\varepsilon_0 = 0$). The specific values of critical concentration N_c (critical temperature T_c)

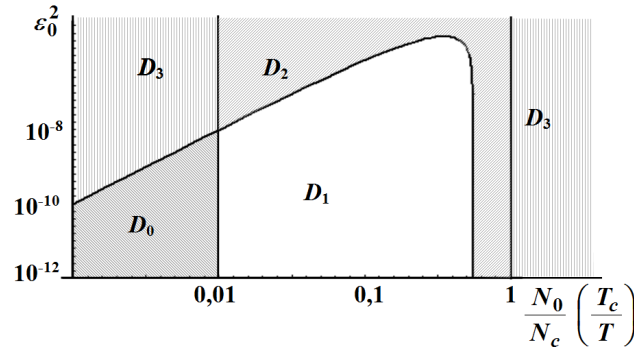


Figure 2. Areas of possible vacancy cluster formation depending on the values ε_0^2 and $N_0/N_c (T_c/T)$: D_0 — the distribution of vacancies is spatially homogeneous; D_1 — there appears an asymmetric vacancy cluster [formula (3.5)]; D_2 — there appears a symmetric vacancy cluster [formula (3.6)]; D_3 — there appears a periodic vacancy lattice [formula (3.7)].

are governed by the elastic constants of a material, by the variation of the crystal volume per one defect, and by the temperature (i.e., average defect concentration).

Substituting the formulae (3.5)–(3.7) into (2.17), we can find the vacancy concentration. Figure 3 qualitatively shows the spatial vacancy concentration distribution (when a symmetric cluster is formed) in the vicinity of a pore having the radius r_0 .

The cluster radius depends on the defect concentration, the elastic constants, and the temperature, and can be determined as follows:

$$r_{\text{cluster}} = \frac{1}{\sqrt{a}} = r_{\text{da}} \sqrt{\left(\frac{N_0}{N_c} - \frac{a_0^2}{r_{\text{da}}^2} \right) \left(1 - \frac{N_0}{N_c} \right)^{-1}} \quad (3.8)$$

or

$$r_{\text{cluster}} = \frac{1}{\sqrt{a}} = r_{\text{da}} \sqrt{\left(\frac{T_c}{T} - \frac{a_0^2}{r_{\text{da}}^2} \right) \left(1 - \frac{T_c}{T} \right)^{-1}}. \quad (3.9)$$

In figure 4, the dependence of the radius of a cluster of vacancies on their relative concentration N_0/N_c [temperature (T_c/T)] in the range $a_0^2/r_{\text{da}}^2 < N_0/N_c < 1$ is presented. At an increase of the vacancy concentration (i.e., a decrease of temperature), the cluster radius increases monotonously and lies in a nano-range.

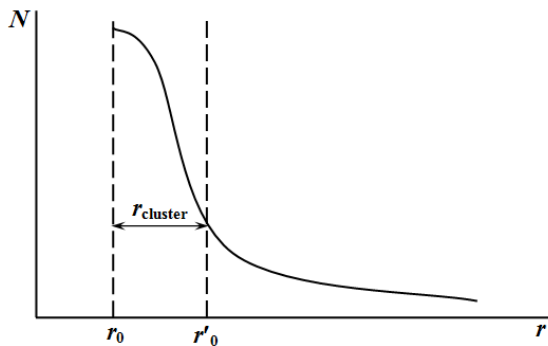


Figure 3. Spatial vacancy concentration distribution in the vicinity of the pore.

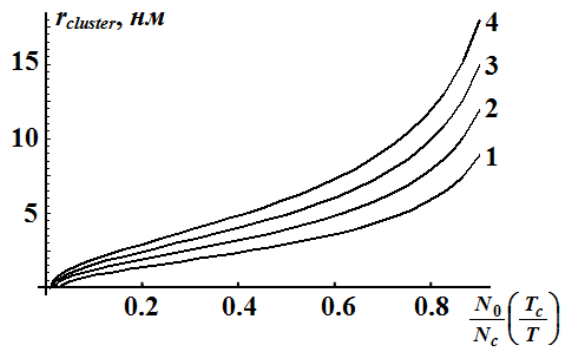


Figure 4. The dependence of the radius of a cluster of vacancies on their concentration: 1 — $r_{\text{da}} = 3$ nm; 2 — $r_{\text{da}} = 4$ nm; 3 — $r_{\text{da}} = 5$ nm; 4 — $r_{\text{da}} = 6$ nm.

4. Diffusion coefficient

Since vacancy clusters or their periodic structures are formed when the vacancy concentration exceeds a certain critical value (at the temperature that is lower than a certain critical value), we may assume that the porosity of the structure will increase due to the pore expansion and the formation of new ones. The size r'_0 of the pore at whose surface a vacancy cluster is formed can be determined in the following way (see figure 3):

$$r'_0 = r_0 + r_{\text{cluster}}. \quad (4.1)$$

Let us find the dependence of the diffusion coefficient D of the impurities of a porous structure on the pore radii within the kinetic theory which is based on the assumption that the size of impurities is much less than the distance between the impurities and between the granules. This approximation is fairly accurate for a structure with a considerable degree of porosity and with a small concentration of impurities.

Diffusion coefficient of gases (impurities):

$$D_0 = \frac{\bar{v}_d^2}{3z}, \quad (4.2)$$

where \bar{v}_d is the arithmetic average velocity of the impurities; z is the number of collisions of an impurity with other impurities and granules of a porous structure per unit of time.

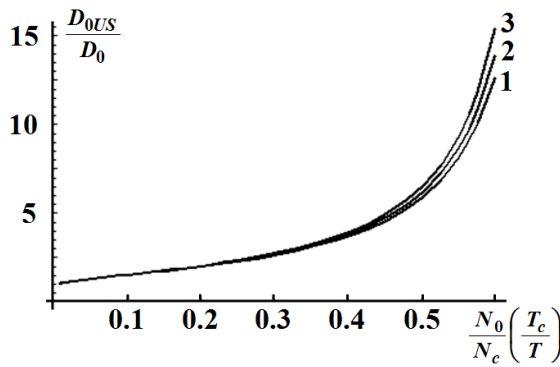


Figure 5. The dependence of the relative change of a coefficient of diffusion D_{0US}/D_0 on the concentration of vacancies (i.e., temperature) at different radii of an impurity: 1 — $r_d = 0.45$ nm; 2 — $r_d = 0.3$ nm; 3 — $r_d = 0.15$ nm.

We define the number of collisions of an impurity with other impurities and granules of a porous structure as the sum of the collisions with impurities and the collisions with granules taken separately.

For this purpose, we assume that the impurities and granules are globules having the radii r_d and $(R_0 - r_0)$, respectively (figure 1). Taking into account that the other impurities are also moving while the granules are motionless, the full number of the impacts can be presented as follows:

$$z = 4\sqrt{2}\pi r_d^2 n_0 \bar{v}_d + \pi (r_d + R_0 - r_0)^2 n_g \bar{v}_d, \quad (4.3)$$

where n_g , n_0 are, respectively, the granule and impurity concentrations at the granule-free bulk. Here, it is considered that the average velocity of the relative motion of an impurity is $\sqrt{2}$ times larger than the velocity of an impurity taking into consideration the immobile granules.

The concentration of impurities at the granule-free bulk can be calculated through the concentration of impurities in the full bulk of the structure n as $n_0 = nR_0^3/[R_0^3 - (R_0 - r_0)^3]$. Then, the diffusion coefficient can be written as follows:

$$D_0 = \frac{\bar{v}_d}{3 \left[4\sqrt{2}\pi r_d^2 n \frac{R_0^3}{R_0^3 - (R_0 - r_0)^3} + \frac{3}{4R_0^3} (r_d + R_0 - r_0)^2 \right]}. \quad (4.4)$$

Taking into account (4.1), we obtain the dependence of the diffusion coefficient on the vacancy cluster size:

$$D_{0US} = \frac{\bar{v}_d}{3 \left[4\sqrt{2}\pi r_d^2 n \frac{R_0^3}{R_0^3 - (R_0 - r_0 - r_{\text{cluster}})^3} + \frac{3}{4R_0^3} (r_d + R_0 - r_0 - r_{\text{cluster}})^2 \right]}. \quad (4.5)$$

In figure 5, the dependence of the relative change of a coefficient of diffusion D_{0US}/D_0 on an average concentration of the vacancies (i.e., temperature) at different radii of an impurity is presented.

Such a dependence shows a monotonously increasing character. In particular, at an increase of the relative concentration of the vacancies at $N_0/N_c = 0.55$, the coefficient of diffusion increases 10 times.

The obtained results are in good agreement with the experimental results. In particular, in [2], it is established that upon ultrasonic processing, the concentration of vacancies in solids non-linearly depends on the amplitude of an ultrasonic wave and temperature. At a temperature below some critical value and at a particular ultrasonic power, a significant increase of the defects of samples (more than an order of magnitude) is observed. Thus, the acoustic and thermal effects have a pronounced synergetic character [2]. In [10], it is experimentally established that when the amplitude of an ultrasonic wave exceeds some critical value in nickel, the pores are formed. Furthermore, at a temperature of $T < 600^\circ\text{C}$, a significant increase of a diffusion coefficient of carbon in nickel (by $2 \div 11$ times) is observed. At a temperature of $T > 600^\circ\text{C}$, the diffusion coefficient does not change upon ultrasonic processing.

5. Conclusions

1. A nonlinear diffusion deformation model is presented for the formation of vacancy nanoclusters and their periodic structures in ultrasonically treated porous material, and the formation criteria are determined according to the deformation amplitude value, the average vacancy concentration and temperature.
2. Within the above mentioned model, it is shown that the diffusion coefficient of porous structures significantly increases at a temperature lower than some critical value, which turns out to be in good agreement with the empirical results.

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Нелінійна модель дифузії домішок у поруватих матеріалах після ультразвукової обробки

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Створено нелінійну теорію дифузії домішок у поруватих матеріалах після ультразвукової обробки. Показано, що при певному значенні амплітуди деформації, середньої концентрації вакансій та температури в результаті впливу ультразвуку можливе формування нанокластерів вакансій та їх періодичних утворень в поруватих матеріалах. Показано, що при температурі, меншій за деяке критичне значення, у поруватих структурах спостерігається значне зростання коефіцієнта дифузії.

Ключові слова: коефіцієнт дифузії, ультразвук, вакансія, пора